STUDY OF OPTOELECTRONIC PROPERTIES OF GA2O3 AND ZNGA2O4 THIN FILMS

This experimental PhD project goals the study of optoelectronic properties of « ultra-wide band gap (UWBG) » oxide semiconductors as Ga2O3 of different polymorphs and ZnGa2O4 spinel.

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GEMaC

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ADDITIONAL INFORMATION

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